

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---|--|------------------|---------|------------------|
| L1 | 138 | (field adj effect adj transistor\$1) and (parallel adj current adj path\$1) | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 15:34 |
| L2 | 36 | 1 and thickness | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 14:56 |
| L3 | 11 | 2 and (oxide adj layer\$1) | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 14:53 |
| L4 | 2 | 1 and ("200" adj Angstroms) | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 14:57 |
| L5 | 6 | 1 and bleed\$3 | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 14:58 |
| L6 | 65 | 1 and threshold | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 14:58 |
| L7 | 48 | (parallel adj current adj path\$1) and (oxide adj layer\$1) | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 15:38 |
| L8 | 2 | 7 and ("200" adj Angstroms) | USPAT; USOCR; EPO; JPO; DERWENT | OR | ON | 2005/03/04 15:38 |